NSN 5961-01-033-6599

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| Inclosure | Material: |
|-----------|-----------|
| molocalo | materiali |

Metal

Overall Length:

0.230 inches

Terminal Length:

0.500 inches

Overall Height:

0.210 inches

Internal Configuration:

Field effect

Electrode Internally-electrically Connected To Case:

Source

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 drain to source voltage and 20.0 drain to gate voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

0.60 amperes drain current

Power Rating Per Characteristic:

1.2 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0